

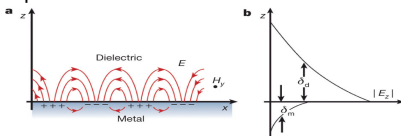


Project Overview

- Modeling, design and characterization of plasmonic detectors developed in collaboration with Boston University.
- Design and modeling of CMOS compatible avalanche photodiodes (APDs) and integrated plasmonic detectors for smart-lighting systems.
- Expected advantages of plasmonic and APD detectors:
 - Simple spectral filtering
 - Simplicity of design
 - High sensitivity
 - Low power consumption
 - Low cost
- Applications: Light intensity measurement, spectral and directional sensing, calibration, and control for smart lighting.

Basic Concept

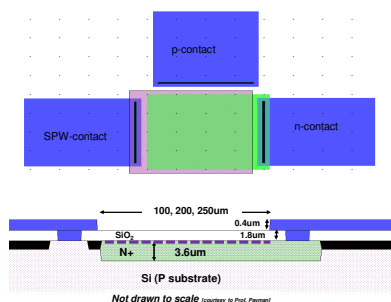
- Surface plasmons (SPs) result from the interaction between light waves and oscillating free electrons on the metal surface.
- The efficient control of photon-plasmon-photon conversion at subwavelength scale gives rise to high-resolution color filtering within the visible electromagnetic spectrum.



Basics of surface plasmon polaritons [1]

Proposed Structures

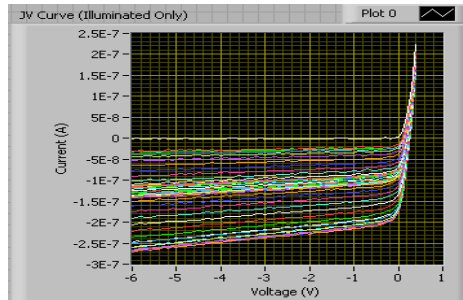
- Plasmonically enhanced CMOS compatible APD device structure.
- Plasmonic structure atop the silicon detector.



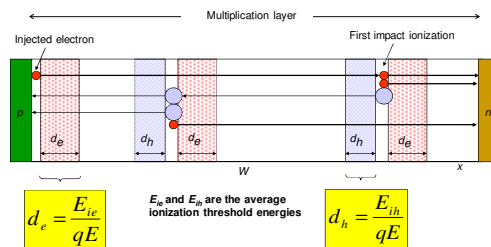
CMOS Compatible Plasmonic PN Photodetector

Design and Modeling

- Characterization results:



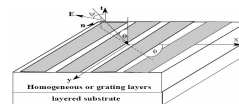
- Modeling
 - ❑ Commercially available Sentaurus technology-computer-aided-design (TCAD) tool was used on the APD structure to:
 - simulate I-V characteristics
 - simulate band profile and electric field distribution along the length of the junction.
 - ❑ Dead-space multiplication theory (DMST) is used to predict avalanche gain, excess noise factor, and breakdown voltage.



Avalanche multiplication: dead space model [2, 3]

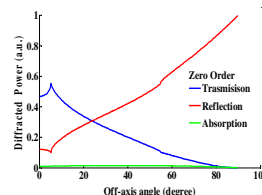
- ❑ Rigorous coupled-wave analysis (RCWA) code was undertaken to analyze integrated plasmonic pn-junction detectors. Predictions include:
 - plasmonic response
 - light transmission spectrum
 - electromagnetic field distribution
 - optical properties of the plasmonic nanostructures.

- Example: Application of RCWA to simple grating structure.



Gold grating atop glass substrate [4]

- UNM code is in good agreement with published results [4].
- Application to plasmonic PD is underway.



Conclusions & Future Work

- Characterization of the developed plasmonic detectors from BU (completed).
- Design and simulation of the plasmonically enhanced CMOS APDs.
- Modeling, design and characterization of different plasmonic PD structures (in collaboration with Prof. Brueck's team).
- Optimization of avalanche gain of CMOS-compatible APDs to improve high sensitivity and unification of responsively across the wavelength 500 nm – 1000 nm range.

Societal Benefits



- Energy sustainability
- Low power consumption



- Increased productivity
- High sensitivity



- Visible light communication
- Spectral calibration
- Wavelength selectivity
- Cost effectiveness
- Potential for time-correlated single-photon-counting for ultrasensitive sensing.

References

- [1] O. Benson, "Assembly of hybrid photonic architectures from nanophotonic constituents," *Nature*, vol. 480, no. 7376, pp. 193–199, 2011.
- [2] M. M. Hayat, Z. Chen, and M. A. Karim, "An analytical approximation for the excess noise factor of avalanche photodiodes with dead space," *IEEE Elect. Dev. Lett*, vol. 20, no. 7, pp. 344–347, 1999.
- [3] M. M. Hayat, B. E. A. Saleh, and M. C. Teich, "Effect of dead space on gain and noise of double-carrier multiplication avalanche photodiodes," *IEEE Trans. Electron Devices*, vol. 39, pp.546–552, 1992.
- [4] B. K. Minhas, "Numerical Modeling of Periodic Structures: Metallic Grids and Metamaterials," PhD dissertation, Electrical Engineering, University of New Mexico, 2003.

Acknowledgements

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